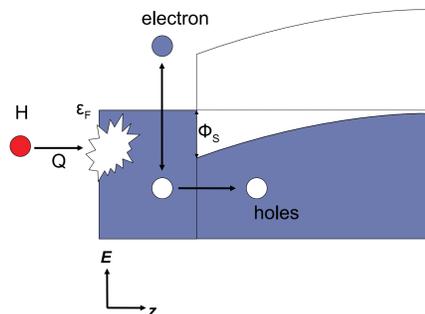


Goals

- Non-adiabatic effects in adsorption on metal surfaces: Calculate the excitation spectrum of electrons and holes
- Develop a method that is more flexible and/or faster than previous methods (TDDFT, electronic friction, Newns-Anderson model)
- Explain the isotope effect in chemicurrent experiments
- Is it necessary to include nonadiabatic effects regarding the spin relaxation?

Experimental setup

- Schottky diode with Fermi energy ϵ_F and Schottky barrier height ϕ_S , consisting of a metal surface on a (usually) p-doped semiconductor
- Atom approaches surface perpendicularly (reaction coordinate Q)
- Excitation of electrons and holes
- Holes (or electrons) can pass the Schottky barrier if their energy is large enough
- Measurement of a (chemi-)current between metal and semiconductor



Theoretical Approach

Perturbation theory

Hamiltonian [1]

$$H_F(t) = \sum_{k,\sigma} \epsilon_{k,\sigma} \psi_{k,\sigma}^\dagger \psi_{k,\sigma} + \sum_{k_1,k_2,\sigma} V_{k_1,k_2,\sigma}(t) \psi_{k_1,\sigma}^\dagger \psi_{k_2,\sigma} = H_0 + V(t)$$

- ϵ_k energy of electrons
- ψ_k^\dagger/ψ_k creator/annihilator of electron
- $V_{k_1,k_2,\sigma}(t)$ matrix elements of perturbation
- σ spin (or)

Perturbative approach

- perturbation rapid and small
- first-order perturbation theory sufficient
- can use unperturbed electronic eigenstates

Difference to previous approaches

- no nonadiabatic wavefunctions / potential (in contrast to TDDFT [2,3])
- can calculate electronic spectrum (in contrast to electronic friction [4])
- direct DFT approach (in contrast to Newns-Anderson model [5])

Spectrum

Matrix elements of perturbation

$$\lambda_{ij} = \int dt \left\langle \epsilon_i \left| \frac{\partial V}{\partial Q} \right| \epsilon_j \right\rangle \frac{dQ}{dt} \exp(i(\epsilon_j - \epsilon_i)t/\hbar)$$

- $|\epsilon_j\rangle$ unperturbed electronic eigenstates
- V effective potential
- Q reaction coordinate

Spectrum of electron-hole pairs

$$P_{ex,eh}(\omega) = \frac{1}{\hbar^2} \sum_{ij} \left| \frac{\lambda_{ij}}{\epsilon_j - \epsilon_i} \right|^2 (f(\epsilon_j) - f(\epsilon_i)) \delta(\omega - (\epsilon_j - \epsilon_i)) \theta(\omega)$$

- $f(\epsilon)$ occupation function (temperature dependent)
- takes into account de-excitation effect

Spectrum of electrons (and holes)

$$P_{ex,e}(\omega) = \frac{1}{\hbar^2} \sum_{ij} \left| \frac{\lambda_{ij}}{\epsilon_j - \epsilon_i} \right|^2 (f(\epsilon_j) - f(\epsilon_i)) \delta(\omega - (\epsilon_j - \epsilon_F)) \theta(\omega)$$

- ϵ_F Fermi-energy

Energy dissipation

$$E_{diss} = \int d\omega \omega P_{ex,eh}(\omega)$$

DFT Calculations

Calculational details

System

H above Al-(111) on-top position

12 layers of Al

$2\sqrt{3} \times 2\sqrt{3}$ unit cell

Quantum-Espresso code

$4 \times 4 \times 1$ Monkhorst-Pack k-point grid

21 Ry cutoff energy

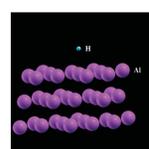
GGA PBE nc pseudopotentials

Dynamics

35 different positions of the H atom

classical dynamics for movement of H atom

one half round trip

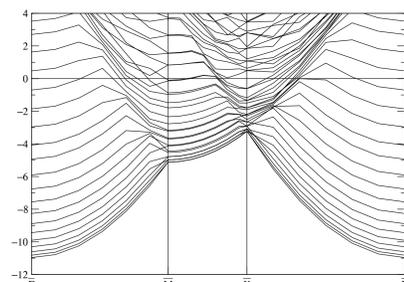


Sketch of our system: Hydrogen on the on-top position of an Al(111) surface

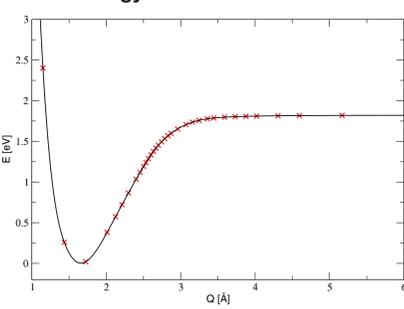
Results

Al lattice constant: 4.06 Å

Surface band structure

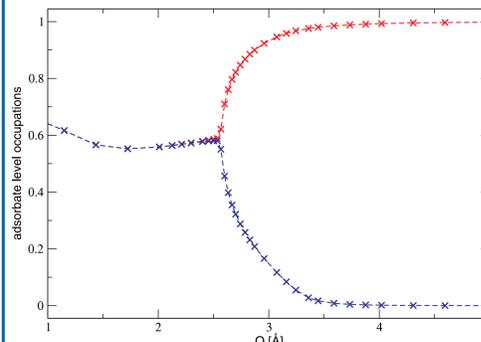


Potential energy

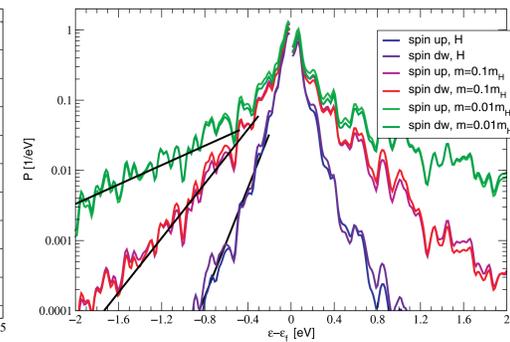


Results

Spin transition

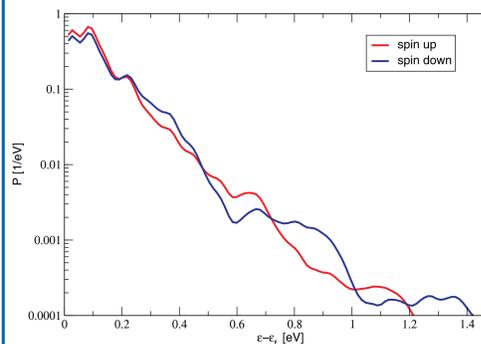


Electron and hole spectra: isotope effect



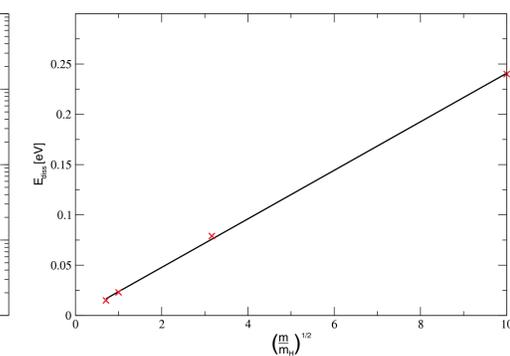
Spectra

e-h pair spectrum: H

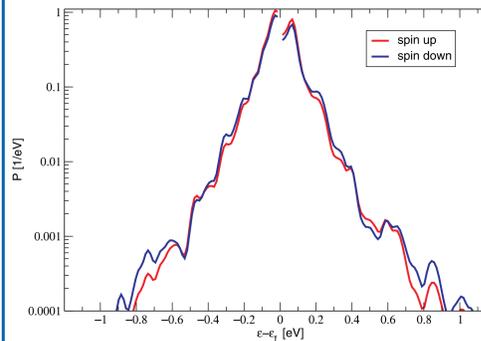


Scaled mass behavior

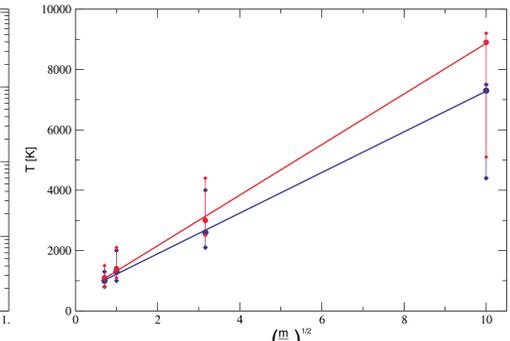
Dissipated energy vs. scaled mass



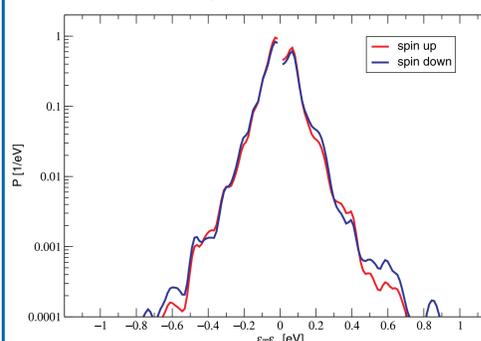
Electron and hole spectrum: H



Fitted temperature vs. scaled mass



Electron and hole spectrum: D



Particles passing the Schottky barrier (0.48 eV)

Isotope	Electrons	Holes
Deuterium	0.000246	0.000175
Hydrogen	0.000781	0.000561
N/N_D	3.17	3.21
$N/N_{D,Experiment}$		3.7 ± 0.7 [6]
H: $m = 0.1 m_H$	0.021502	0.014713
N/N_H	27.53	26.23
H: $m = 0.01 m_H$	0.088775	0.064376
N/N_H	113.67	114.75

Discussion

Achievements

- DFT approach
- New method for calculation of spectra and energy loss due to electronic excitations
- Method is computationally fast, and can be implemented in existing codes (post-processing)
- It is formally not necessary to include spin relaxation effects (no divergences)
- Unlike in the friction picture there are excitations with a finite energy
- Spin effects are within the error bar
- We can explain the isotope effect
- Scaled mass behavior

Future Goals

- Further investigation of spin effect
- Molecular adsorption
- Other systems

Acknowledgements

This work was supported by the SFB 616 'Energy Dissipation at surfaces'.

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